

HF/VHF/UHF RF power N-channel MOSFET

Datasheet - production data

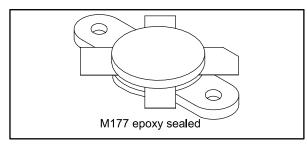
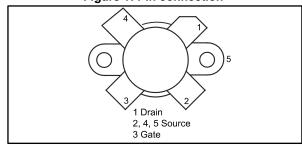


Figure 1: Pin connection



Features

- High power capability
- Pout = 350 W min. with 22 dB gain@30 MHz
- Psat = 450 W
- Low R_{DS(on)}
- Thermally enhanced packing for lower junction temperatures
- Gold metallization
- Excellent thermal stability
- Common source configuration

Description

The SD2943 is a gold metallized N-channel MOS field-effect RF power transistor. It is used for 50 V DC large signal applications up to 150 MHz. The SD2943 offers a 20% higher power saturation than the SD2933, and is ideal for ISM applications where reliability and ruggedness are critical factors.

Table 1: Device summary

| Order code Marking | | Marking | Package | Packing |
|--------------------|---------|-----------------------|---------|--------------|
| | SD2943W | SD2943 ⁽¹⁾ | M177 | Plastic tray |

Notes:

⁽¹⁾For more details please refer to Section 6: "Marking, packing and shipping specifications".

Contents SD2943

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SD2943 Electrical data

1 Electrical data

1.1 Maximum ratings

T_{CASE} = 25 °C

Table 2: Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|-------------------------------------|--|-------------|------|
| V _{(BR)DSS} ⁽¹⁾ | Drain source voltage | 130 | V |
| V _{DGR} | Drain-gate voltage (R _{GS} = 1 MΩ) | 130 | V |
| V_{GS} | Gate-source voltage | ±40 | V |
| I _D | Drain current | 40 | Α |
| P _{DISS} | Power dissipation | 648 | W |
| TJ | Max. operating junction temperature | +200 | °C |
| Eas | Avalanche energy, single pulse (ID = 53 A, 800 μ H coil) | 1100 | mJ |
| T _{STG} | Storage temperature | -65 to +150 | °C |

Notes:

 $^{(1)}T_J = 150 \, ^{\circ}C$

1.2 Thermal data

Table 3: Thermal data

| Symbol | Parameter | Value | Unit |
|--------|-------------------------------------|-------|------|
| RthJC | Junction-to-case thermal resistance | 0.27 | °C/W |

Electrical characteristics SD2943

2 Electrical characteristics

T_{CASE} = 25 °C

Table 4: Static

| Symbol | Test conditions | | Min. | Тур. | Max. | Unit | |
|-------------------------------------|-------------------------|---------------------------|-----------|------|------|------|-----|
| V _{(BR)DSS} ⁽¹⁾ | $V_{GS} = 0 V$ | $I_{DS} = 200 \text{ mA}$ | | 130 | | | V |
| I _{DSS} | $V_{GS} = 0 V$ | $V_{DS} = 50 \text{ V}$ | | | | 200 | μΑ |
| I _{GSS} | $V_{GS} = 20 \text{ V}$ | $V_{DS} = 0 V$ | | | | 500 | nA |
| V _{GS(Q)} | V _{DS} = 10 V | $I_D = 250 \text{ mA}$ | | 2 | | 4 | V |
| V _{DS(ON)} | V _{GS} = 10 V | I _D = 20 A | | | | 2 | V |
| G _{FS} | V _{DS} = 10 V | I _D = 10 A | | 10 | | | mho |
| C _{ISS} | $V_{GS} = 0 V$ | $V_{DS} = 50 \text{ V}$ | f = 1 MHz | | 830 | | pF |
| Coss | V _G s = 0 V | $V_{DS} = 50 \text{ V}$ | f = 1 MHz | | 470 | | pF |
| C _{RSS} | V _{GS} = 0 V | $V_{DS} = 50 \text{ V}$ | f = 1 MHz | | 35 | | pF |

Notes:

 $^{(1)}T_J = 150 \, ^{\circ}C$

Table 5: Dynamic

| Symbol | Test conditions | Min. | Тур. | Max. | Unit |
|------------------|---|------|------|------|------|
| Pout | $V_{DD} = 50 \text{ V}$ $I_{DQ} = 250 \text{ mA}$ $f = 30 \text{ MHz}$ | 350 | 450 | | W |
| G _{PS} | $V_{DD} = 50 \text{ V}$ $I_{DQ} = 250 \text{ mA}$ $P_{OUT} = 350 \text{ W}$ $f = 30 \text{ MHz}$ | 22 | 25 | | dB |
| η _D | $V_{DD} = 50 \text{ V}$ $I_{DQ} = 250 \text{ mA}$ $P_{OUT} = 350 \text{ W}$ $f = 30 \text{ MHz}$ | 60 | 65 | | % |
| Load mismatch | $V_{DD} = 50 \text{ V}$ $I_{DQ} = 250 \text{ mA}$ $P_{OUT} = 350 \text{ W}$ $f = 30 \text{ MHz}$ All phase angles | 3:1 | | | VSWR |

Table 6: GFS sorts

| Symbol | Value |
|--------|-------------|
| A | 10 to 10.99 |
| В | 11 to 11.99 |
| С | 12 to 12.99 |
| D | 13 to 13.99 |
| E | 14 to 14.99 |
| F | 15 to 15.99 |
| G | 16 to 16.99 |
| Н | 17 to 18 |

SD2943 Impedance data

3 Impedance data

Figure 2: Impedance data

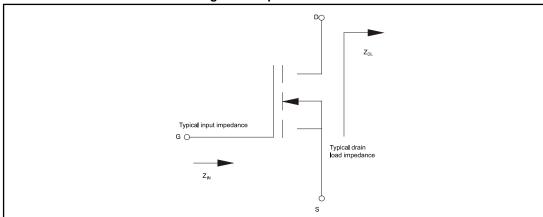
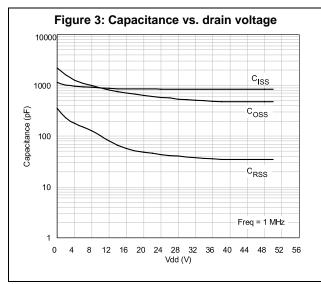


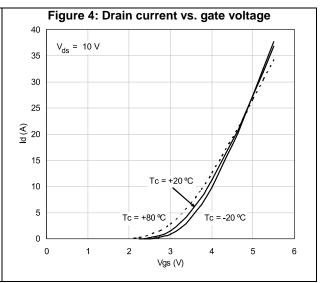
Table 7: Impedance data

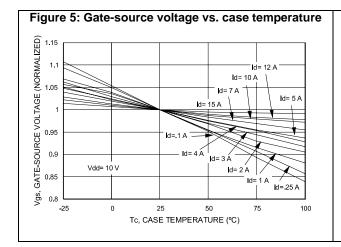
| f | $Z_IN(\Omega)$ | $Z_DL(\Omega)$ |
|---------|----------------|----------------|
| 30 MHz | 1.3 - j 2.9 | 3.1 + j 2.3 |
| 108 MHz | 1.4 - j 2.4 | 1.9 + j 1.4 |
| 175 MHz | 1.4 - j 2.2 | 1.7 + j 1.6 |

Typical performance SD2943

4 Typical performance







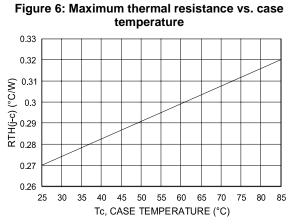
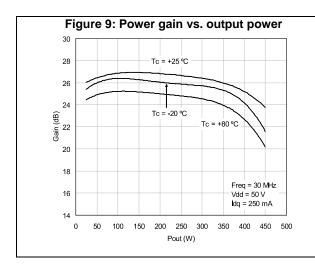
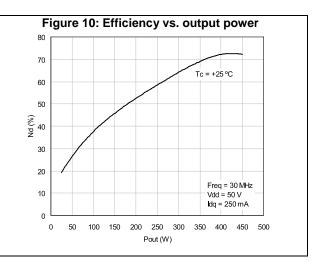
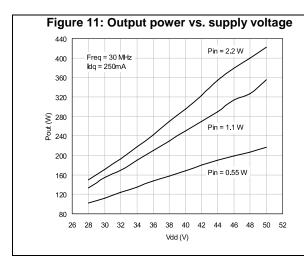


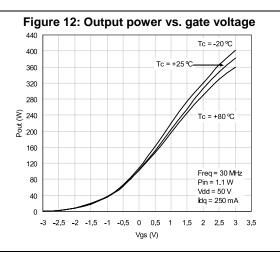
Figure 7: Output power vs. input power 500 450 400 Vdd = 50 V 350 300 Vdd = 40 V 250 200 150 100 Frea = 30 MHz 50 0.0 0.5 1.0 1.5 2.0 3.0 3.5 Pin (W)

Figure 8: Output power vs. input power (at different temperature) 500 Tc = +25 ℃ Tc = -20 °C 450 Tc = +80 °C 400 350 300 250 200 150 100 Freq = 30 MHz Vdd = 50 V Idq = 250 mA 50 0 0.0 0.5 1.0 1.5 2.0 2.5 3.5 4.0 Pin (W)



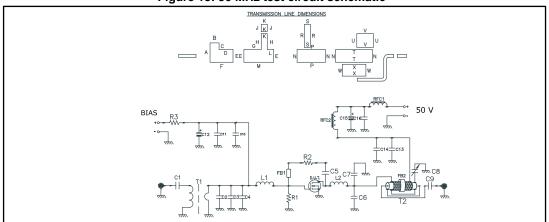






5 Test circuit (175 MHz)

Figure 13: 30 MHz test circuit schematic





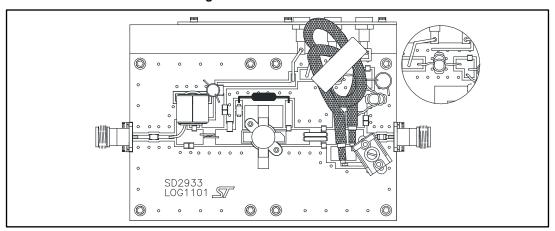
Dimensions at component symbols are references for component placement. Gap between ground and transmission files are 0.056[1.42] (typ.). Transmission line is not 1:1 scale. Input and output transmission line are 50 Ω .

Table 8: 30 MHz test circuit part list

| Component | Description |
|---------------------------|--|
| C1, C9 | 0.01 μF / 500 V surface mount ceramic chip capacitor |
| C2, C3 | 750 pF ATC 700B surface mount ceramic chip capacitor |
| C4 | 300 pF ATC 700B surface mount ceramic chip capacitor |
| C5, C10, C11, C14, C16 | 10000 pF ATC 200B surface mount ceramic chip capacitor |
| C6 | 510 pF ATC 700B surface mount ceramic chip capacitor |
| C7 | 300 pF ATC 700B surface mount ceramic chip capacitor |
| C8 | 175-680 pF type 46 standard trimmer capacitor |
| C12 | 47 μF / 63 V aluminum electrolytic radial lead capacitor |
| C13 | 1200 pF ATC 700B surface mount ceramic chip capacitor |
| C15 | 100 μF / 63 V aluminum electrolytic radial lead capacitor |
| R1, R3 | 1 kΩ 1 W surface mount chip resistor |
| R2 | 560 Ω 2 W wire-wound axil lead resistor |
| T1 | HF 2-30 MHz surface mount 9:1 transformer |
| T2 | RG - 142B/U 50 Ω coaxial cable OD = 0.165[4.18] L 15"[381.00] covered with 15"[381.00] tinned copper tubular brand 13/65" [5.1] width |
| L1 | 1 3/4 turn air-wound 16 AWG ID = 0.219 [5.56] poly-coated magnet wire |
| L2 | 1 3/4 turn air-wound 12 AWG ID = 0.250 [6.34] bus bar wire |
| RFC1, RFC2 | 3 turns 14 AWG wire through fair rite toroid |
| FB1 | Surface mount shield bead |

| Component | Description |
|-----------|---|
| FB2 | Toroid |
| PCB | ULTRALAM 2000. 0.030" THK, εr = 2.55, 2 Oz ED CU both sides |

Figure 14: 30 MHz test circuit





Both the SD2933 and the SD2943 device use the same PCB.

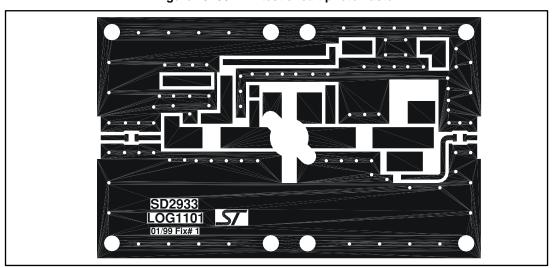


Figure 15: 30 MHz test circuit photomaster

6 Marking, packing and shipping specifications

Table 9: Packing and shipping specifications

| Order code | Packing | Pieces per tray | Dry pack humidity | G _{FS} code | Lot code |
|------------|--------------|-----------------|----------------------|----------------------|-----------|
| SD2943W | Plastic tray | 25 | < 10% | Not mixed | Not mixed |

Figure 16: SD2943 marking layout

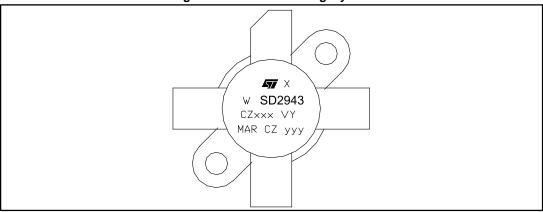


Table 10: Marking specifications

| Symbol | Description | |
|--------|--------------------------------|--|
| W | Wafer process code | |
| X | G _{FS} sort | |
| CZ | Assembly plant | |
| XXX | Last 3 digits of diffusion lot | |
| VY | Diffusion plant | |
| MAR | Country of origin | |
| CZ | Test and finishing plant | |
| у | Assembly year | |
| уу | Assembly week | |

SD2943 Package information

7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: **www.st.com**. ECOPACK® is an ST trademark.

7.1 M177 (.550 DIA 4L NHERM WFLG) package information

Ø.125/3.18 NIMFULL R

135/3.43

0 SEATING PLANE

Figure 17: M177 (.550 DIA 4L N/HERM W/FLG) package outline

Table 11: M177 (.550 DIA 4L N/HERM W/FLG) package mechanical data

| Dim. | mm | | |
|------|-------|------|-------|
| | Min. | Тур. | Max. |
| Α | 5.72 | | 5.97 |
| В | 6.73 | | 6.96 |
| С | 21.84 | | 22.10 |
| D | 28.70 | | 28.96 |
| Е | 13.84 | | 14.10 |
| F | 0.08 | | 0.18 |
| G | 2.49 | | 2.74 |
| Н | 3.81 | | 4.32 |
| I | | | 7.11 |
| J | 27.43 | | 28.45 |
| K | 15.88 | | 16.13 |

Revision history SD2943

8 Revision history

Table 12: Document revision history

| Date | Revision | Changes | |
|-------------|----------|--|--|
| 18-Oct-2005 | 1 | First issue. | |
| 04-Jan-2006 | 2 | Complete version. | |
| 24-Aug-2011 | 3 | Inserted Chapter 7: Marking, packing and shipping specifications. Minor text changes. | |
| 10-Aug-2015 | 4 | Updated <i>Table 2.: Absolute maximum rating</i> . Minor text changes. | |
| 02-Dec-2016 | 5 | Updated <i>Table 2: "Absolute maximum ratings"</i> . Minor text changes. | |

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